

TRIPLE ELEMENT THYRISTOR OVERVOLTAGE PROTECTORS

TISP70xxL1 (VLV) OvervoltageProtectors

D Package (Top View)

Three Terminal Very Low Voltage (VLV) Protection Ion-Implanted Breakdown Region

Device	V _{DRM} V	V _(BO) V
'7015L1	8	15
'7038L1	28	38

Protection for Signal, Data and Control Lines

- ISDN
- T1/E1
- Ethernet
- RS232 & RS485

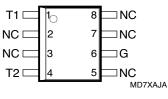
Low Capacitance

Rated for International Surge Wave Shapes

Voltage	Standard	I _{PPSM}
Waveshape	Standard	Α
2/10	GR-1089-CORE	200
1.2/50	IEC 61000-4-5	100
10/700	TIA/EIA-IS-968 ITU-T K.20/45/21	50
10/1000	GR-1089-CORE	30

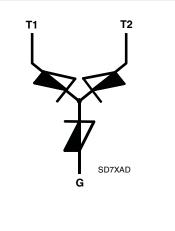
IEC 61000-4-2 Immunity Ratings

Contact	3 kV
Air	2 L/



NC - No internal connection

Device Symbol



W UL Recognized Components

Description

The TISP70xxL1 series are 3-point overvoltage protectors designed for protecting against metallic (transverse mode) and simultaneous longitudinal (common mode) impulses. Each terminal pair has the same voltage limiting values and surge current capability.

These devices are designed to limit overvoltages between signal, data and control port conductors, connected to terminals T1 and T2, and a protective ground, G. Each terminal pair has a symmetrical voltage-triggered bidirectional thyristor characteristic (Figure 1). Overvoltages are initially clipped by breakdown clamping until the voltage rises to the breakover level, which causes the device to crowbar into a low-voltage on state. This low-voltage on state causes the current resulting from the overvoltage to be safely diverted through the device. The device holding current will normally be higher than the available short circuit d.c. system current, causing the protector to switch off as the diverted current subsides.

How To Order

Device Package		Carrier	Order As		
TISP7015L1	D (8-pin, Small-outline)	R (Embossed Tape Reeled)	TISP7015L1DR-S		
TISP7038L1	D (8-pin, Small-outline)	R (Embossed Tape Reeled)	TISP7038L1DR-S		

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The TISP70xxL1 is guaranteed to withstand the listed international ESD (ElectroStatic Discharge), and lightning impulses in both polarities. Terminals marked NC do not have any internal connections and may be left floating or tied to some circuit point. The TISP7038L1 is a functional replacement for the TPN3021.

Absolute Maximum Ratings, T_J = 25 °C (Unless Otherwise Noted)

Rating		Symbol	Value	Unit
Repetitive peak off-state voltage	TISP7015L1 TISP7038L1	V _{DRM}	± 8 ± 28	v
Non-repetitive peak on-state pulse current (see Notes 1 and 2)				
2/10 (Telcordia GR-1089-CORE, 2/10 voltage wave shape)			200	
1/20 (ITU-T K.22, 1.2/50 voltage wave shape, also VDE0878)			100	
8/20 (IEC 61000-4-5, Figure 12 generator, 1.2/50 voltage wave shap	e)	I	100	•
10/160 (TIA/EIA-IS-968 (formally FCC Part 68), 10/160 voltage wave	e shape)	IPPSM	75	A
5/310 (ITU-T k.20/21, 10/700 voltage wave shape, also IEC 61000-4-5 and VDE0433) 10/560 (TIA/EIA-IS-968 (formally FCC Part 68), 10/560 voltage wave shape)			50	
			40	
10/1000 (Telcordia GR-1089-CORE, 10/1000 voltage wave shape)			30	
Non-repetitive peak on-state current (see Note 1)				
16.7 ms (60 Hz) full sine wave			9	
20 ms (50 Hz) full sine wave		I _{TSM}	8	А
0.2 s 50 Hz/60 Hz a.c.		-15M	3	
2.0 s 50 Hz/60 Hz a.c.			1.5	
Junction temperature		ТJ	-40 to +150	°C
Storage temperature range		T _{stg}	-65 to +150	°C

NOTES: 1. Initially the TISP70xxL1 must be in thermal equilibrium at the specified TA. The surge may be repeated after the TISP70xxL1 returns to its initial conditions.

2. These non-repetitive rated currents are peak values of either polarity.

EMC Immunity Test Ratings, $T_A = 25$ °C (Unless Otherwise Noted)

Rating		Value	Unit
Level 3 open-circuit voltage, IEC 61000-4-2, 2001-4, ESD generator, also ITU-T K.20			
contact discharge air discharge	V _{O/C}	6 8	kV

Electrical Characteristics, T_J = 25 °C (Unless Otherwise Noted)

Parameter Test Conditions		Min	Тур	Мах	Unit	
I _{DRM}	Repetitive peak off- state current	$V_D = \pm V_{DRM}$			±4	μA
V _(BO)	Breakover voltage	dv/dt = ±250 V/ms, R _{SOURCE} = 300 Ω TISP701 TISP703			±15 ±38	V
I _(BO)	Breakover current	dv/dt = ± 250 V/ms, R _{SOURCE} = 300 Ω			±300	mA
I _H	Holding current	$IT = \pm 5 A$, di/dt = $\pm 30 mA/ms$	±30			mA

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Electrical Characteristics, T_J = 25 °C (Unless Otherwise Noted) (Continued)

	Parameter	Test Conditions		Min	Тур	Мах	Unit
C _{KA}	Off-state capacitance	f = 1 MHz, V_d = 1 V rms, V_D = 0 (see Note 3)	TISP7015L1 TISP7038L1		24 17		pF

NOTE 3: Value for any terminal pair, three-terminal guarded measurement with zero voltage bias on the unmeasured terminal.

Thermal Characteristics

	Parameter	Test Conditions	Min	Тур	Мах	Unit
$R_{\Theta J A}$	Junction to free air thermal resistance	$P_{tot} = 0.8 \text{ W}, T_A = 25 \text{ °C}, 5 \text{ cm}^2, \text{ FR4 PCB}$			170	°C/W

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Parameter Measurement Information

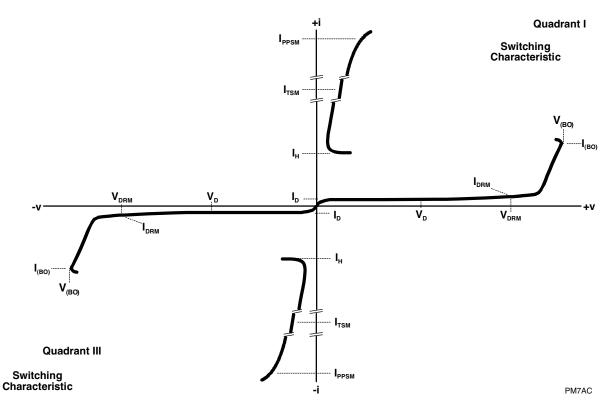
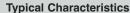


Figure 1. Voltage-Current Characteristic for any Terminal Pair

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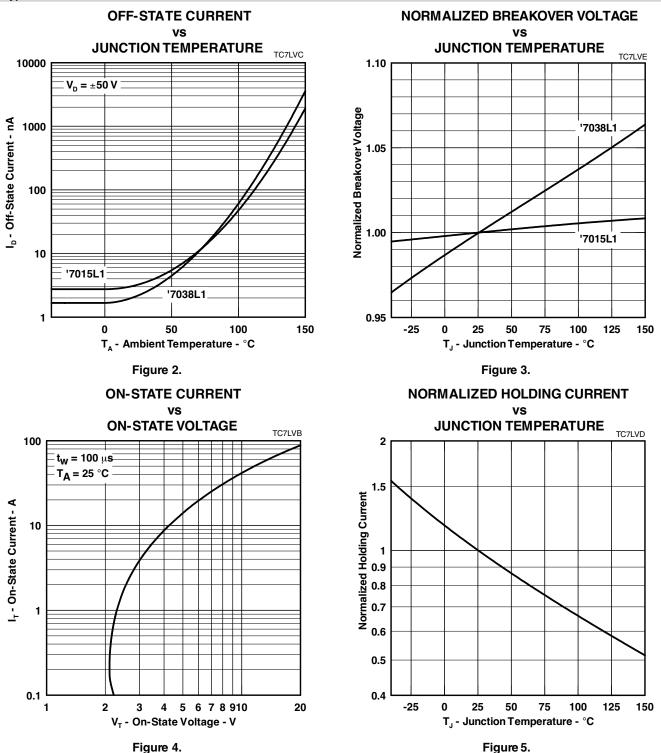
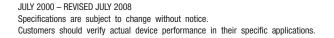


Figure 4.



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Typical Characteristics

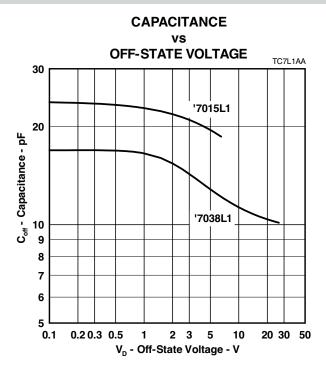


Figure 6.

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Rating and Thermal Information

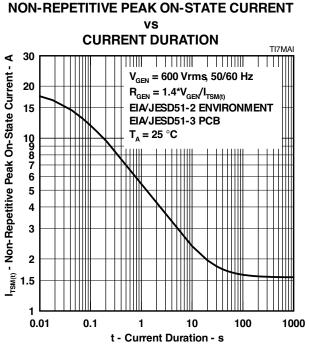


Figure 7.

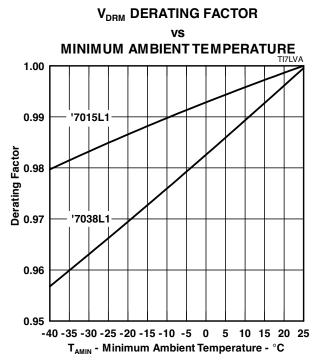


Figure 8.

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MECHANICAL DATA

Device Symbolization Code

Devices will be coded as below.

Device	Symbolization Code
TISP7015L1DR-S	7015L1
TISP7038L1DR-S	7038L1

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